#### **FEATURES:**

- N channel FET switches with no parasitic diode to Vcc
  - Isolation under power-off conditions
  - No DC path to Vcc or GND
  - 5V tolerant in OFF and ON state
- 5V tolerant I/Os
- Low Ron 4Ω typical
- · Flat Ron characteristics over operating range
- Rail-to-rail switching 0 5V
- Bidirectional dataflow with near-zero delay: no added ground bounce
- Excellent Ron matching between channels
- Vcc operation: 2.3V to 3.6V
- High bandwidth up to 500MHz
- · LVTTL-compatible control Inputs
- · Undershoot Clamp Diodes on all switch and control Inputs
- · Low I/O capacitance, 4pF typical
- · Available in QSOP and TSSOP packages

#### **APPLICATIONS:**

- · Hot-swapping
- Multiplexing/demultiplexing
- · Low distortion analog switch
- · Replaces mechanical relay
- ATM 25/155 switching

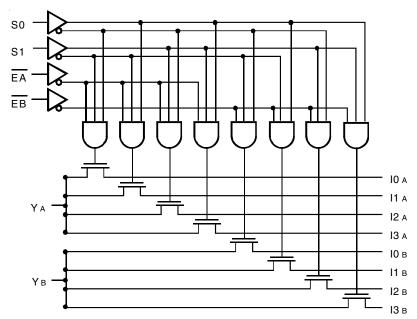
#### **DESCRIPTION:**

The QS3VH253 HotSwitch Dual 4:1 multiplexer/demultiplexer is a high bandwidth bus switch. The QS3VH253 has very low ON resistance, resulting in under 250ps propagation delay through the switch. The Select (Sx) inputs control the data flow. The multiplexers/demultiplexers are enabled when the Enable  $(\overline{\text{EA}}, \overline{\text{EB}})$  inputs are low. In the ON state, the switches can pass signals up to 5V. In the OFF state, the switches offer very high impedance at the terminals.

The combination of near-zero propagation delay, high OFF impedance, and over-voltage tolerance makes the QS3VH253 ideal for high performance communication applications.

The QS3VH253 is characterized for operation from -40°C to +85°C.

### **FUNCTIONAL BLOCK DIAGRAM**

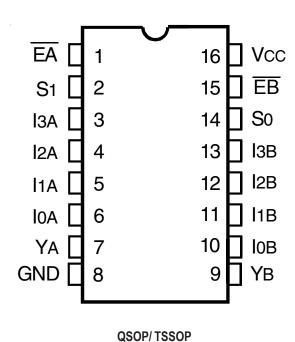


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**INDUSTRIAL TEMPERATURE RANGE** 

**FEBRUARY 2014** 

### **PIN CONFIGURATION**



### **ABSOLUTE MAXIMUM RATINGS**(1)

Symbol	Description	Max	Unit
VTERM <sup>(2)</sup>	SupplyVoltage to Ground	-0.5 to +4.6	V
VTERM <sup>(3)</sup>	DC Switch Voltage Vs	-0.5 to +5.5	V
VTERM <sup>(3)</sup>	DC Input Voltage Vเท	-0.5 to +5.5	V
VAC	AC Input Voltage (pulse width ≤20ns)	-3	V
lout	DC Output Current (max. sink current/pin)	120	mA
Tstg	Storage Temperature	-65 to +150	°C

#### NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause
  permanent damage to the device. This is a stress rating only and functional operation of
  the device at these or any other conditions above those indicated in the operational
  sections of this specification is not implied. Exposure to absolute maximum rating
  conditions for extended periods may affect reliability.
- 2. Vcc terminals.
- 3. All terminals except Vcc .

### **CAPACITANCE** (TA = +25°C, F = 1MHz, VIN = 0V, VOUT =

0 <b>%</b> ymbol	Parameter <sup>(1)</sup>		Тур.	Max.	Unit
CIN	Control Inputs		3	5	pF
CI/O	Quickswitch Channels	Demux	4	6	pF
	(Switch OFF)	Mux	11	15	
CI/O	Quickswitch Channels	Demux	12	16	pF
	(Switch ON)	Mux	12	16	

#### NOTE:

1. This parameter is guaranteed but not production tested.

### **FUNCTION TABLE**(1)

Ena	Enable		Select		outs	
ĒĀ	ĒΒ	S <sub>1</sub>	S <sub>0</sub>	YA	Yв	Function
Н	Х	Х	Х	Z	Х	Disable A
Х	Н	Х	Х	Х	Z	Disable B
L	L	L	L	10a	10в	S1 - 0 = 0
L	L	L	Н	I1a	I1в	S1 - 0 = 1
L	L	Н	L	I2A	<b>12</b> B	S1 - 0 = 2
L	L	Н	Н	I3 <sub>A</sub>	13в	S1 - 0 = 3

**TOP VIEW** 

### NOTE:

- 1. H = HIGH Voltage Level
  - L = LOW Voltage Level
  - X = Don't Care
  - Z = High-Impedence

### **PIN DESCRIPTION**

Pin Names	I/O	Description
lxx	I	Data Inputs
S0, S1	Ι	Select Input
EA, EB	I	Enable Input
Ya, Yb	0	Data Outputs

### DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

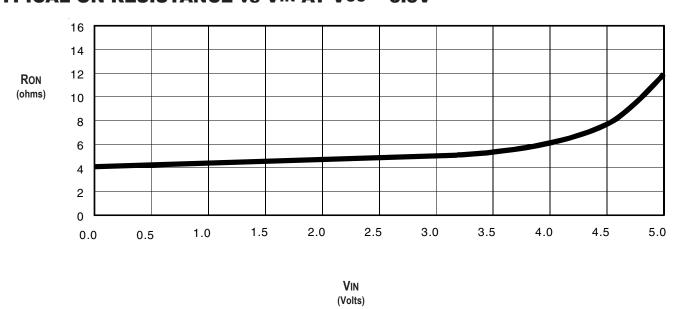
Following Conditions Apply Unless Otherwise Specified:

Industrial: TA = -40°C to +85°C,  $VCC = 3.3V \pm 0.3V$ 

Symbol	Parameter	Test C	Conditions		Min.	Typ. <sup>(1)</sup>	Max.	Unit
VIH	Input HIGH Voltage	Guaranteed Logic HIGH	Vcc = 2.3V to 2.7	V	1.7	_	_	V
		for Control Inputs	Vcc = 2.7V to 3.6	SV .	2	_	_	
VIL	Input LOW Voltage	Guaranteed Logic LOW	Vcc = 2.3V to 2.7	V	_	_	0.7	V
		for Control Inputs	Vcc = 2.7V to 3.6	SV .	_	_	0.8	
lin	Input Leakage Current (Control Inputs)	0V ≤ VIN ≤ VCC		_	_	±1	μΑ	
loz	Off-State Current (Hi-Z)	0V ≤ Vouт ≤ 5V, Switches OFF		_	_	±1	μΑ	
loff	Data Input/Output Power Off Leakage	VIN or VOUT 0V to 5V, VCC = 0V		_	_	±1	μΑ	
		Vcc = 2.3V	VIN = 0V	Ion = 30mA	_	6	8	
Ron	Switch ON Resistance	Typical at Vcc = 2.5V	VIN = 1.7V	Ion = 15mA	_	7	9	Ω
		Vcc = 3V	VIN = 0V	Ion = 30mA	_	4	6	
			VIN = 2.4V	Ion = 15mA	_	5	8	

#### NOTE:

### TYPICAL ON RESISTANCE vs Vin AT Vcc = 3.3V



<sup>1.</sup> Typical values are at Vcc = 3.3V and Ta = 25°C.

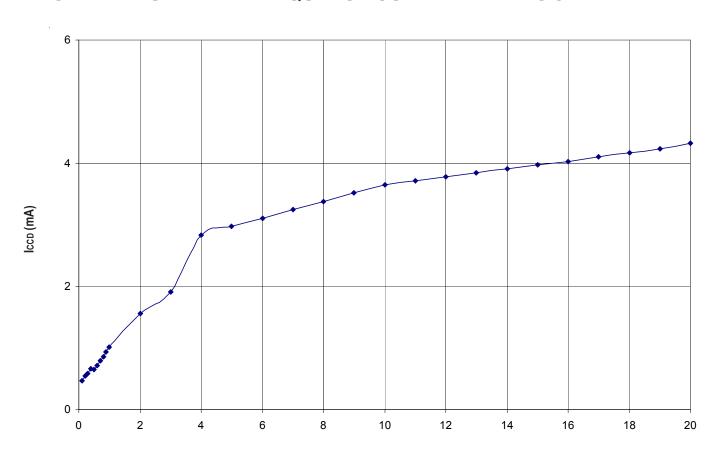
### **POWER SUPPLY CHARACTERISTICS**

Symbol	Parameter	Test Conditions <sup>(1)</sup>	Min.	Тур.	Max.	Unit
Iccq	Quiescent Power Supply Current	Vcc = Max., Vin = GND or Vcc, f = 0	_	2	4	mA
Δlcc	Power Supply Current (2,3) per Input HIGH	Vcc = Max., Vin = 3V, f = 0 per Control Input	_	_	30	μA
ICCD	Dynamic Power Supply Current(4)	Vcc = 3.3V, A and B Pins Open, Control Inputs	See Typical	ICCD vs Enabl	e Frequency	graph below
		Toggling @ 50% Duty Cycle				

#### NOTES:

- 1. For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.
- 2. Per input driven at the specified level. Mux/demux pins do not contribute to Δlcc.
- 3. This parameter is guaranteed but not tested.
- 4. This parameter represents the current required to switch internal capacitance at the specified frequency. The mux/demux inputs do not contribute to the Dynamic Power Supply Current. This parameter is guaranteed but not production tested.

### TYPICAL ICCD vs ENABLE FREQUENCY CURVE AT VCC = 3.3V



**ENABLE FREQUENCY (MHz)** 

### **SWITCHING CHARACTERISTICS OVER OPERATING RANGE**

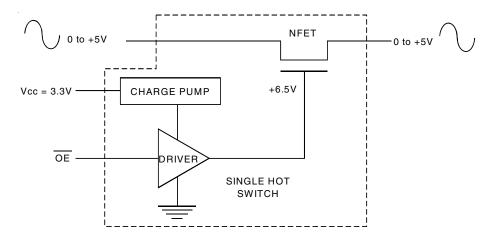
 $T_A = -40$ °C to +85°C

		$Vcc = 2.5 \pm 0.2V^{(1)}$		$Vcc = 3.3 \pm 0.3 V^{(1)}$		
Symbol	Parameter	Min. <sup>(4)</sup>	Max.	Min. <sup>(4)</sup>	Max.	Unit
tPLH	Data Propagation Delay <sup>(2,3)</sup>	_	0.2	_	0.2	ns
<b>t</b> PHL	Yx to lxx or lxx to Yx					
tsel	Select Time	1.5	9	1.5	8	ns
	S to Yx					
tpzh	Enable Time	1.5	9	1.5	9	ns
tPZL	Sx to lxx					
tphz	Disable Time	1.5	8	1.5	8	ns
tPLZ	Sx to lxx					
tpzh	Enable Time	1.5	9	1.5	8	ns
tPZL	Ex to Yx or Ixx					
tphz	Disable Time	1.5	8	1.5	8	ns
tPLZ	Ex to Yx or Ixx					
fExorSx	Operating Frequency - Enable <sup>(2,5)</sup>		10		20	MHz

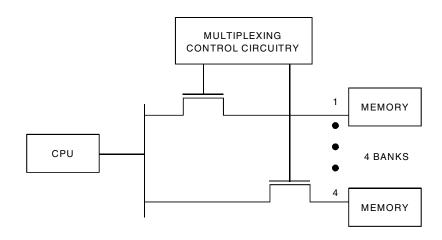
#### NOTES:

- 1. See Test Conditions under TEST CIRCUITS AND WAVEFORMS.
- 2. This parameter is guaranteed but not production tested.
- 3. The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.2ns at C<sub>L</sub> = 50pF. Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.
- 4. Minimums are guaranteed but not production tested.
- 5. Maximum toggle frequency for Sx or  $\overline{\text{Ex}}$  control input (pass voltage > Vcc, Vin = 5V, RLOAD  $\geq$  1M $\Omega$ , no CLOAD).

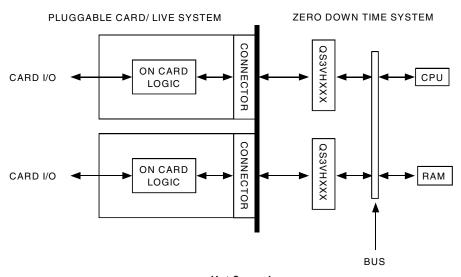
### SOME APPLICATIONS FOR HOTSWITCH PRODUCTS



Rail-to-Rail Switching



Multiplexing/Demultiplexing

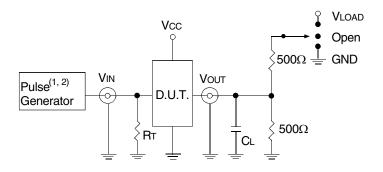


Hot-Swapping

### **TEST CIRCUITS AND WAVEFORMS**

### **TEST CONDITIONS**

Symbol	$Vcc^{(1)}=3.3V\pm0.3V$	Vcc <sup>(2)</sup> = 2.5V ± 0.2V	Unit
VLOAD	6	2 x Vcc	V
VIH	3	Vcc	V
VT	1.5	Vcc/2	V
VLZ	300	150	mV
VHZ	300	150	mV
CL	50	30	pF



**Test Circuits for All Outputs** 

#### **DEFINITIONS:**

CL = Load capacitance: includes jig and probe capacitance.

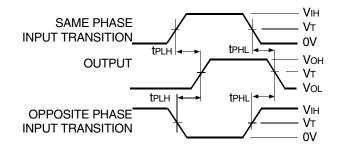
RT = Termination resistance: should be equal to ZouT of the Pulse Generator.

#### NOTES:

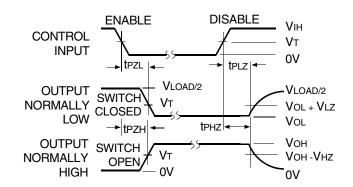
- 1. Pulse Generator for All Pulses: Rate  $\leq$  10MHz; tF  $\leq$  2.5ns; tR  $\leq$  2.5ns.
- 2. Pulse Generator for All Pulses: Rate  $\leq$  10MHz; tF  $\leq$  2ns; tR  $\leq$  2ns.

### **SWITCH POSITION**

Test	Switch
tplz/tpzl	Vload
tpHz/tpzH	GND
tPD	Open



**Propagation Delay** 

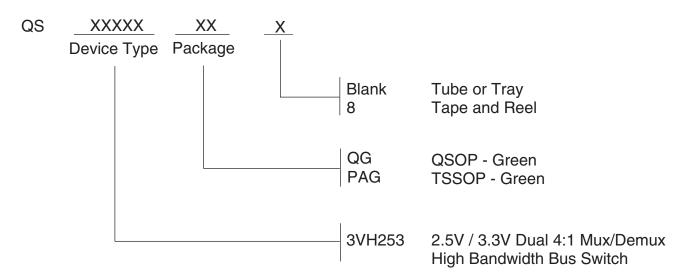


#### NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

#### **Enable and Disable Times**

### **ORDERING INFORMATION**



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